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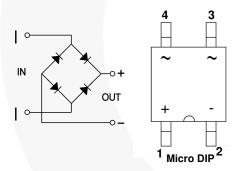




# MDB10SV 1.2 A, 1000 V, Micro-DIP, Single-Phase Bridge Rectifier

#### **Features**

- Optimized V<sub>F</sub>: 1.015 V Maximum at 1.2 A
- $I_{F(AV)} = 1.2 A$
- I<sub>FSM</sub> = 50 A
- · MDB10SS and MDB10S Socket Compatible
- Glass-Passivated Junctions
- Requires Only 35 mm<sup>2</sup> of Board Space
- Low Package Profile: 1.45 mm Typical, 1.60 mm Maximum
- · RoHS Compliant
- Halogen Free
- Qualified with IR/convection Solder Reflow (J-STD-020) and Wave Soldering (JESD22-A111)



## Description

With the ever-pressing need to improve power supply efficiency and reliability, the MDB10SV sets a new standard in small form-factor, efficient, robust, bridge rectifier performance.

The design offers improved efficiency by achieving a 1.2 A  $V_F$  of 1.015 V maximum at 25°C. This lower  $V_F$  results in cooler and more efficient power supply operation.

The design enhances reliability with a 50 A I<sub>FSM</sub> rating to absorb high surge currents, improved I<sup>2</sup>t ratings, and supporting a rated breakdown voltage of 1000 V. Finally, the MDB10SV achieves all this in a small formfactor micro-DIP package, offering a maximum height of 1.6 mm, and requiring only 35 mm<sup>2</sup> of board space.

# Ordering Information

Part Number	Top Mark	Package	Packing Method
MDB10SV	MDB10V	Micro DIP	Tape and Reel

# **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25^{\circ}\text{C}$  unless otherwise noted.

Symbol	Parameter	Value	Unit
V <sub>RRM</sub>	Maximum Repetitive Peak Reverse Voltage	1000	V
V <sub>RMS</sub>	Maximum RMS Voltage	700	V
$V_{DC}$	Maximum DC Blocking Voltage	1000	V
I <sub>F(AV)</sub>	Average Rectified Forward Current <sup>(1)</sup>	1.2	Α
I <sub>FSM</sub>	Peak Forward Surge Current <sup>(2)</sup>	50	Α
I <sup>2</sup> t	I <sup>2</sup> t Rating for Fusing (t < 8.3 ms)	10.4	A <sup>2</sup> S
T <sub>J</sub>	Operating Junction Temperature Range	-55 to +150	°C
T <sub>STG</sub>	Storage Temperature Range	-55 to +150	°C

#### Notes:

- 1. 8.3 ms single half-sine wave, R-load,  $T_A = 25$ °C.
- 2. 8.3 ms single half-sine wave, single pulse,  $T_J = 25$ °C, compliant with MIL standard.

#### Thermal Characteristics(3)

Symbol	Parameter	Conditions	Max.	Unit	
R <sub>θJA</sub>	Thermal Resistance, Junction to Ambient	Multi-Die Measurement (Maximum Land Pattern: 12 x 12 mm)	55	°C/W	
		Multi-Die Measurement (Minimum Land Pattern: 0.95 x 1.65 mm)	115	- C/ <b>VV</b>	
ΨJL	Thermal Characterization Parameter, Junction to Lead	Single-Die Measurement (Maximum and Minimum Land Pattern)	18	°C/W	

#### Note:

3. The thermal resistances ( $R_{\theta JA}$  &  $\psi_{JL}$ ) are characterized with the device mounted on the following FR4 printed circuit boards, as shown in Figure 1 and Figure 2, PCB size: 76.2 x 114.3 mm.

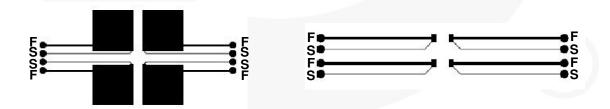


Figure 1. Maximum Pads of 2 oz Copper

Figure 2. Minimum Pads of 2 oz Copper

# **Electrical Characteristics**

Values are at  $T_A = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions		Value		Unit
Symbol	Parameter			Тур.	Max.	Onit
		$I_F$ = 0.3 A, 300 $\mu$ s Pulse, 1% Per Diode	Duty Cycle,	0.850		
V <sub>F</sub>	Maximum Forward Voltage	$I_F$ = 1.0 A, 300 μs Pulse, 1% Duty Cycle, Per Diode		0.930		V
		$I_F$ = 1.2 A, 300 μs Pulse, 1% Duty Cycle, Per Diode		0.940	1.015	
1	Maximum Reverse	At V <sub>RWM</sub> , Pulse Measure-	T <sub>A</sub> = 25°C	0.1	10.0	^
I <sub>R</sub>	Current	ment, Per Diode	T <sub>A</sub> = 125°C	95.0		μΑ
CJ	Typical Junction Capacitance	V <sub>R</sub> = 4 V, f = 1 MHz		14		pF
t <sub>rr</sub>	Typical Reverse-Recovery Time	I <sub>F</sub> = 0.5 A, I <sub>RM</sub> = 1 A, I <sub>R(REC</sub>	) = 0.25 A	1430		ns

# **Typical Performance Characteristics**

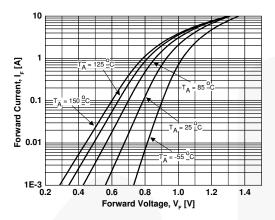


Figure 3. Typical Instantaneous Forward Voltage Per Leg

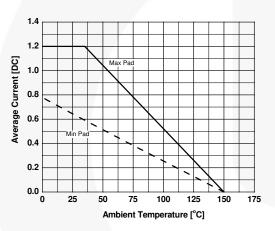


Figure 5. Forward Current Derating Curve

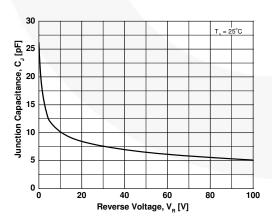


Figure 7. Typical Junction Capacitance

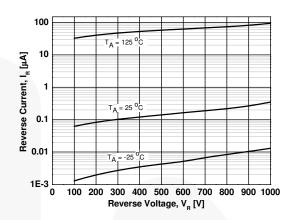
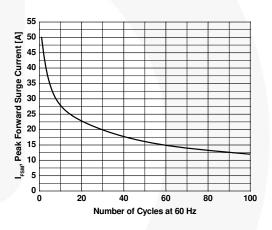
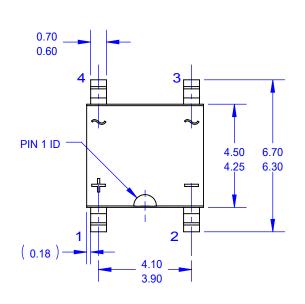
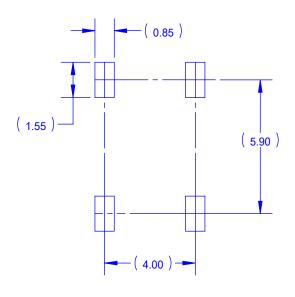


Figure 4. Typical Reverse-Voltage Current Characteristics



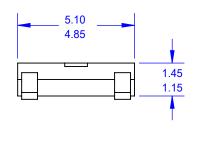
**Figure 6. Surge Current Derating Curve** 



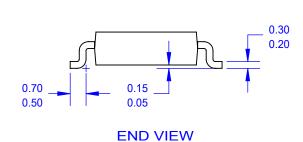


**TOP VIEW** 

#### LAND PATTERN RECOMMENDATION







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